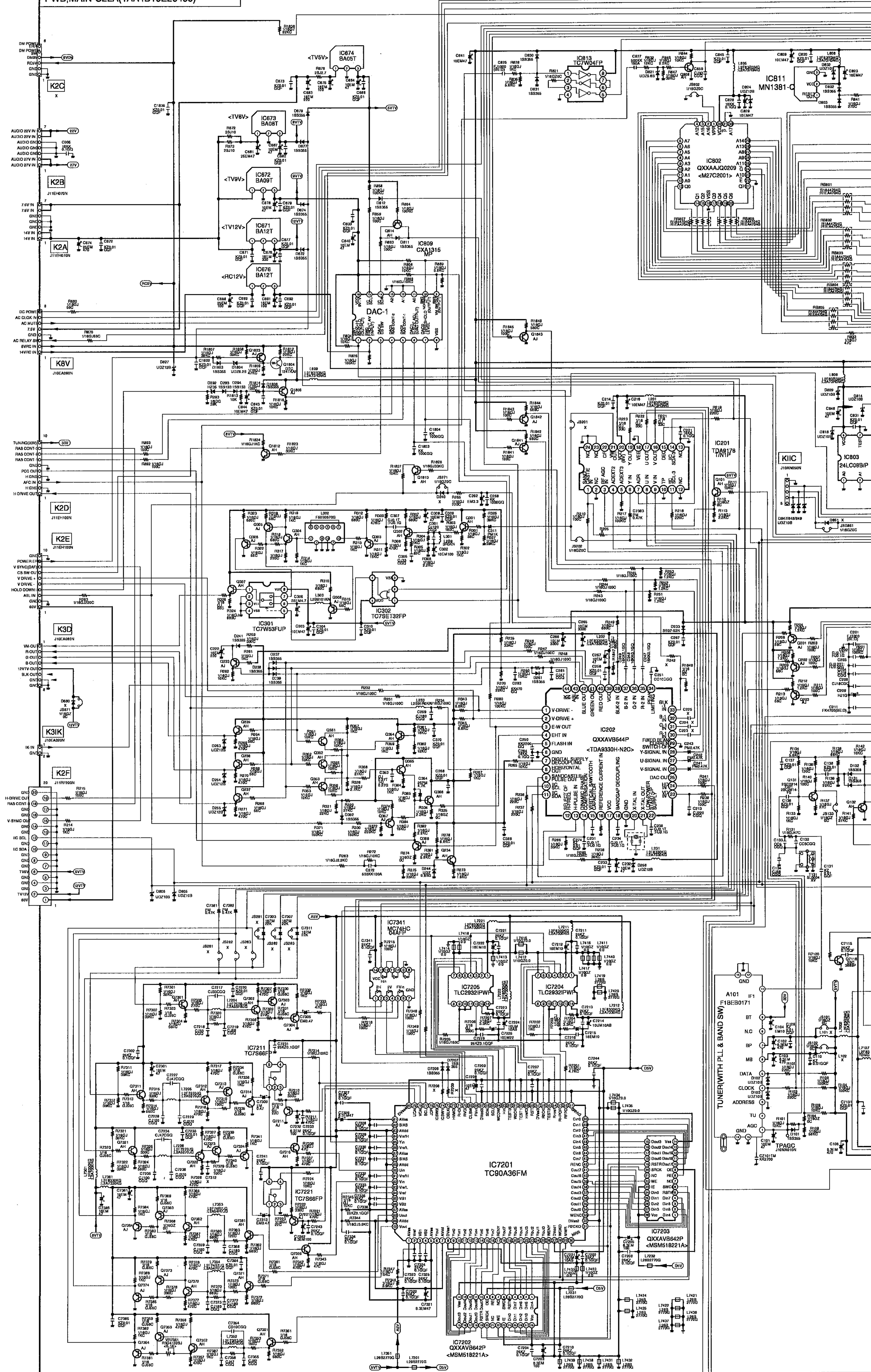
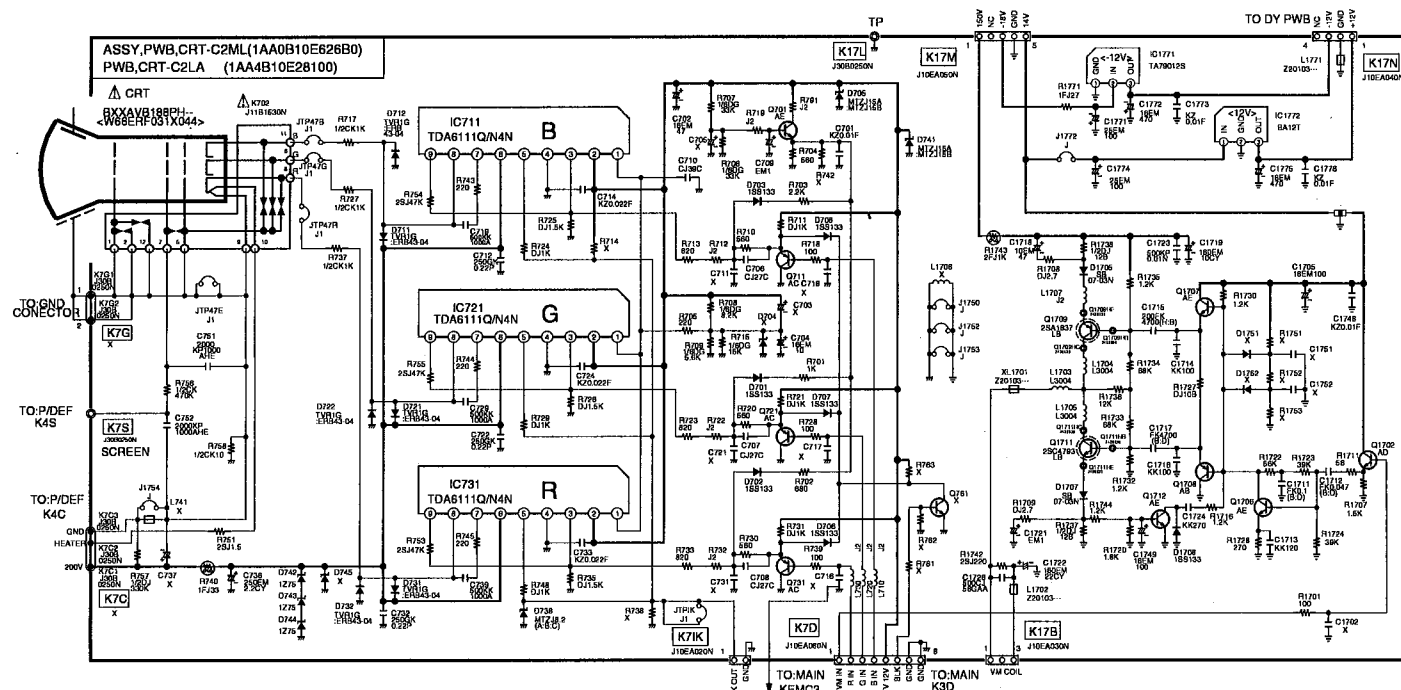
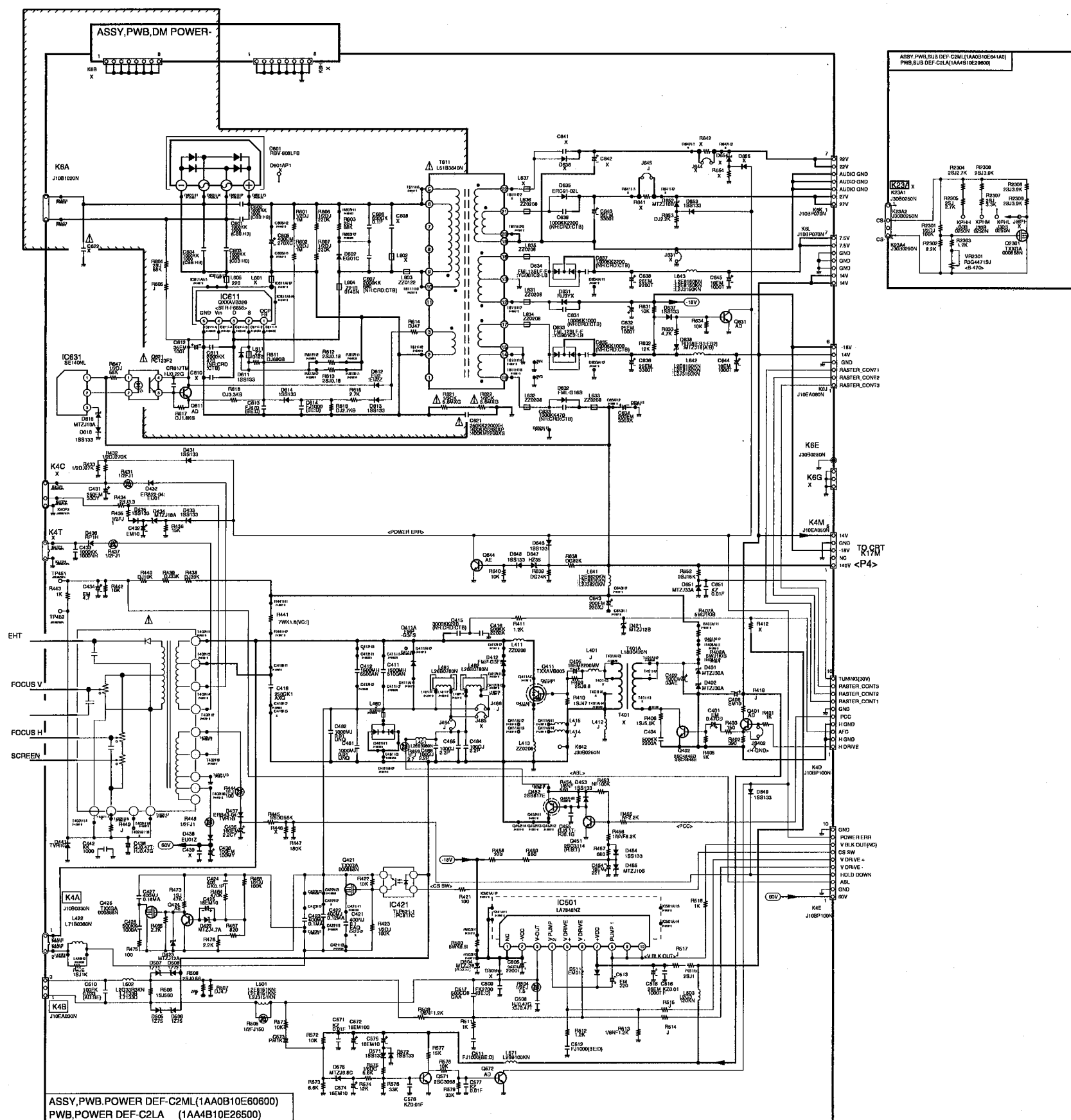


ASSY,PWB,MAIN-C2ML(1AA0B10E605B0)
PWB,MAIN-C2LA(1AA4B10E26400)





8. This circuit diagram covers a basic or representative chassis only. There may be some components or partial circuit differences between the actual chassis and the circuit diagram.
9. Diode 1S1555 may be replaced with 1S2473, 1S2076 or DS472 unless otherwise noted.
- Transistor 2SC536(Q,R,S), 2SC1740(Q,R,S), 2SC945A(Q,R,P) or 2SC1815(G,O,Y) unless otherwise noted.
- Transistor 2SA608(E,F) may be replaced with 2SA933(Q,R), 2SA564(QA,RA), or 2SA1015(O,Y) unless otherwise noted.

Expression of capacitance and resistance in circuit diagram.

Capacitance (Example)

1000 C M 2000 D

- Characteristic
- Capacitance value (220pF)
- Tolerance (±20%)
- Kind (Ceramic)
- Rated voltage (1,000V)

Resistance (Example)

1/2 N J 1.2

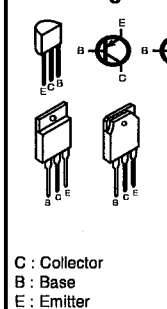
- Resistance value (1.2Ω)
- Tolerance (±5%)
- Kind (M.carbon)
- Rated wattage (1/2W)

J = ± 5%
K = ± 10%
M = ± 20%

T, A, U, D : Electrolytic
C, K, B : Ceramic
F : Mylar film
M, N : Polypropylene
Z : Metallized paper

D : Carbon
S : Metallized carbon
N : Oxide metallized
W : Wire winding
C : Solid

Terminal guide



Chip Components

